

6.730 Physics for Solid State Applications

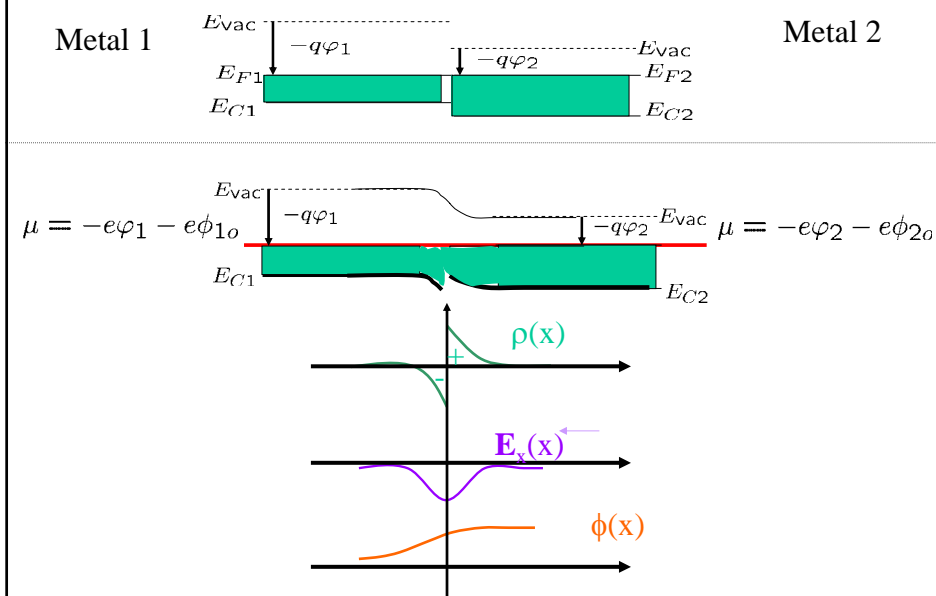
Lecture 27: Quasi-fermi levels and Non-equilibrium

Outline

- Review of Equilibrium of inhomogeneous materials
 - Metal-Metal, PN and hetero-junctions- fermi levels
- Rate Equations for Non-equilibrium Electrons
- Quasi-Fermi Levels

April 12, 2004

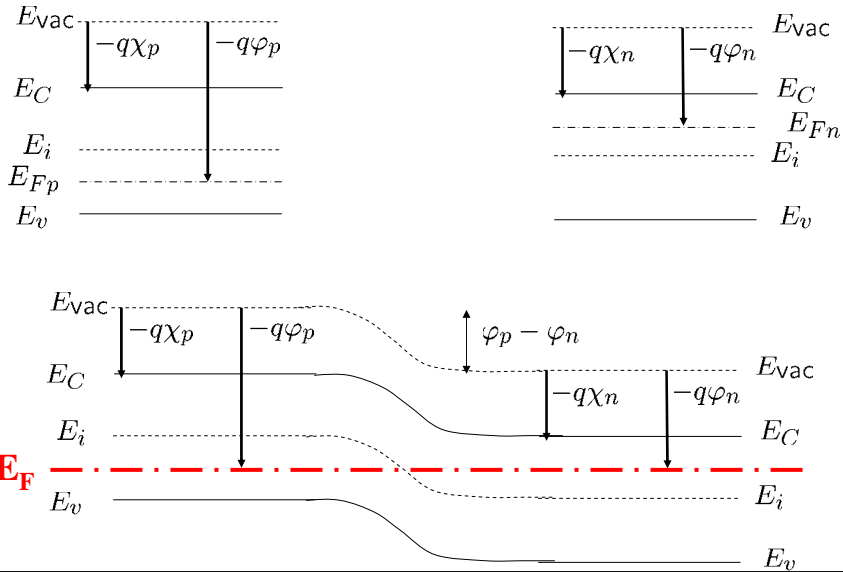
Metal-Metal contact



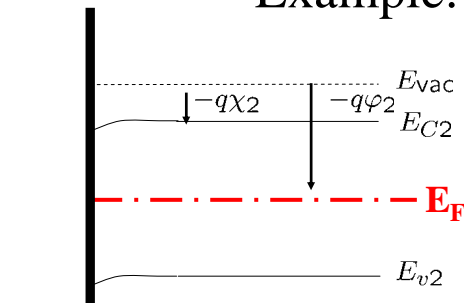
Example: PN-junction

p-doped Si

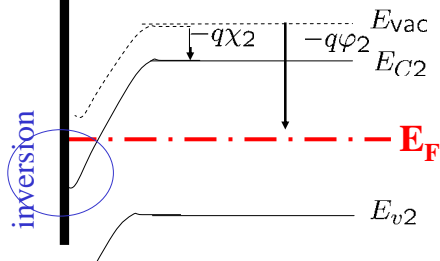
n-doped Si



Example: MOS

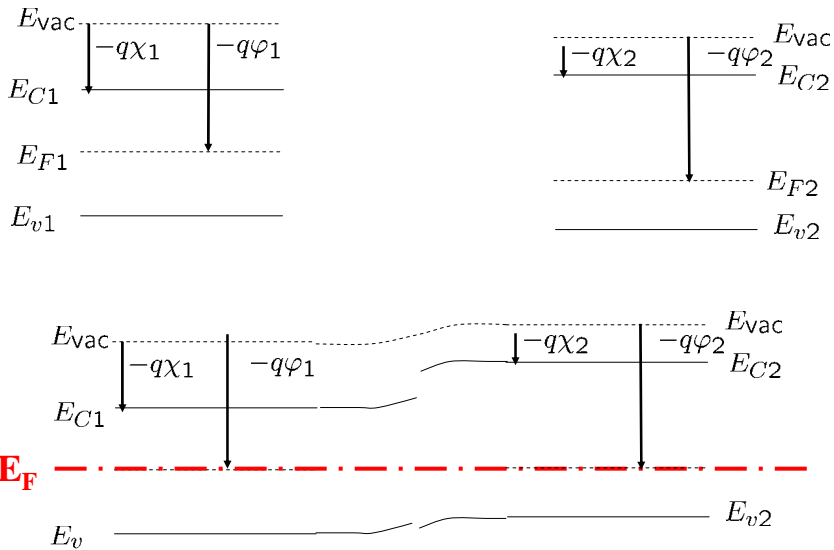


Metal electrode to control the amount of bandbending at the surface



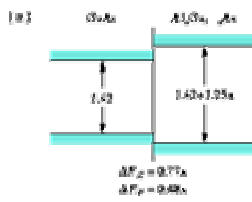
Inversion region looks like the electrons are near the surface, confined by the potential, resulting in a 2D electron gas parallel to the surface.

Example: hetero-junction

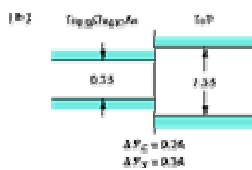


Species of Heterojunctions

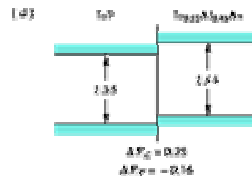
Type I



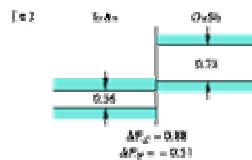
Type I



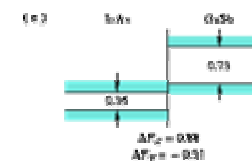
Type II



Type III



Type III



<http://www.utdallas.edu/~frenseley/technical/hetphys>

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Lecture 27: Quasi-fermi levels and Non-equilibrium

Outline

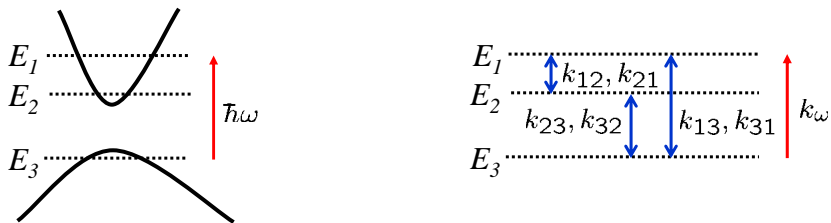


- PN and hetero-junctions- fermi levels
- **Rate Equations for Non-equilibrium Electrons**
- **Quasi-Fermi Levels**

April 12, 2004

Near Equilibrium Electron Distributions

Informative Example: Optical Excitations



k_{12}, k_{21} Intraband scattering: electron-electron
electron-acoustic phonon

k_{23}, k_{32}
 k_{13}, k_{31} Interband scattering: electron-hole
electron-phonon with defects

What are $f_1, f_2,$ & f_3 under illumination (non-equilibrium) ?

Classical Rate Equation Formalism

number of electrons = number of states \times probability of occupancy

$$n_1 = N_1 f_1 \quad n_2 = N_2 f_2 \quad n_3 = N_3 f_3$$

$$\begin{aligned} \frac{dn_1}{dt} = & -k_{12} N_1 f_1 N_2 (1-f_2) + k_{21} N_2 f_2 N_1 (1-f_1) \\ & -k_{13} N_1 f_1 N_3 (1-f_3) + k_{31} N_3 f_3 N_1 (1-f_1) + k_w N_3 f_3 N_1 (1-f_1) \end{aligned}$$

$$\begin{aligned} \frac{dn_2}{dt} = & +k_{12} N_1 f_1 N_2 (1-f_2) - k_{21} N_2 f_2 N_1 (1-f_1) \\ & -k_{23} N_2 f_2 N_3 (1-f_3) + k_{32} N_3 f_3 N_2 (1-f_2) \end{aligned}$$

$$\frac{dn_3}{dt} = - \left(\frac{dn_1}{dt} + \frac{dn_2}{dt} \right) \quad \text{assume total number of electrons in } N_1, N_2, \text{ \& } N_3 \text{ is constant}$$

Rate Constants in Equilibrium

Detailed Balance

$$\text{In equilibrium: } f^o(E) = \frac{1}{1 + \exp\left(\frac{E-E_F}{k_B T}\right)}$$

Detailed balance:

In equilibrium, each scattering process balances with its inverse

$$k_{12} N_1 f_1^o N_2 (1-f_2^o) = k_{21} N_2 f_2^o N_1 (1-f_1^o)$$

$$\begin{aligned} k_{21} &= k_{12} \frac{f_1^o}{(1-f_1^o)} \frac{(1-f_2^o)}{f_2^o} \\ &= k_{12} e^{-(E_1-E_F)/k_B T} e^{(E_2-E_F)/k_B T} \\ &= k_{12} \underbrace{e^{-(E_1-E_2)/k_B T}}_{A_{12}} \end{aligned}$$

$$k_{21} = k_{12} A_{12} \quad k_{32} = k_{23} A_{23} \quad k_{31} = k_{13} A_{13}$$

Rate Equations

Assume the rate constants don't change out of equilibrium...

$$N_1 \frac{df_1}{dt} = -k_{12} N_1 N_2 [f_1(1 - f_2) - A_{12} f_2(1 - f_1)] \\ - k_{13} N_1 N_3 [f_1(1 - f_3) - A_{13} f_3(1 - f_1)] + k_w N_3 N_1 f_3(1 - f_1)$$

$$N_2 \frac{df_2}{dt} = +k_{12} N_1 N_2 [f_1(1 - f_2) - A_{12} f_2(1 - f_1)] \\ - k_{23} N_2 N_3 [f_2(1 - f_3) - A_{23} f_3(1 - f_2)]$$

Steady-State Solutions Non-equilibrium

$$\frac{dn_3}{dt} = \frac{dn_1}{dt} = \frac{dn_2}{dt} = 0$$

$$\frac{dn_2}{dt} = 0 \Rightarrow \frac{f_1(1 - f_2) - A_{12} f_2(1 - f_1)}{f_2(1 - f_3) + A_{23} f_3(1 - f_2)} = \frac{k_{23} N_3}{k_{12} N_1}$$

For example when intraband scattering is much faster than interband scattering...

$$N_1 \sim N_3 \quad k_{12} \gg k_{31}, k_{23}$$

$$f_1(1 - f_2) - A_{12} f_2(1 - f_1) \approx 0$$

$$\frac{f_1}{(1 - f_1)} \approx A_{12} \frac{(1 - f_2)}{f_2}$$

Steady-State Solutions Non-equilibrium

Equilibrium Fermi-Dirac distribution:

$$f^o(E) = \frac{1}{1 + \exp\left(\frac{E-E_F}{k_B T}\right)}$$

Non-equilibrium Quasi-Fermi-Dirac distribution is defined by:

$$f_j(E_j) = \frac{1}{1 + \exp\left(\frac{E_j - E_{F_j}}{k_B T}\right)}$$

$$\frac{f_1}{(1 - f_1)} \approx A_{12} \frac{(1 - f_2)}{f_2}$$

$$e^{-(E_1 - E_{F_1})/k_B T} \approx e^{-(E_1 - E_2)/k_B T} e^{(E_2 - E_{F_2})/k_B T}$$

$$E_{F_1} \approx E_{F_2}$$

Intraband states have same chemical potential

→ in 'equilibrium' with each other because of fast intraband scattering

Steady-State Solutions Non-equilibrium

$$N_1 \frac{df_1}{dt} \rightarrow 0 = -k_{12} N_1 N_2 [f_1(1 - f_2) - A_{12} f_2(1 - f_1)] - k_{13} N_1 N_3 [f_1(1 - f_3) - A_{13} f_3(1 - f_1)] + k_\omega N_3 N_1 f_3(1 - f_1)$$

$$E_{F_3} = E_{F_1} - k_B T \ln \left[\frac{k_\omega e^{(E_1 - E_3)/k_B T} + k_{13}}{k_{13}} \right]$$

Interband states have different chemical potentials

unless $k_\omega \rightarrow 0$ $E_{F_3} = E_{F_1}$

Counting in Non-equilibrium Semiconductors

Equilibrium

$$n_o = N_c \exp\left(\frac{-(E_c - E_{F_o})}{k_B T}\right)$$

$$p_o = N_v \exp\left(\frac{-(E_{F_o} - E_v)}{k_B T}\right)$$

$$n_o p_o = N_c N_v \exp\left(\frac{-E_g}{k_B T}\right) = n_i^2$$

Quasi-equilibrium

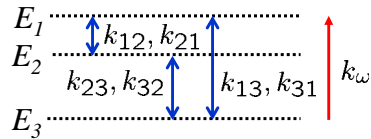
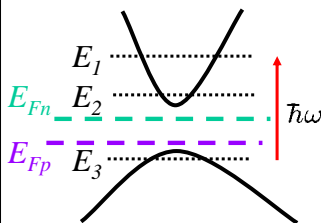
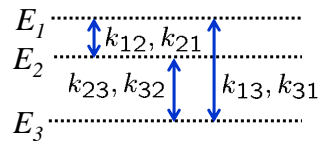
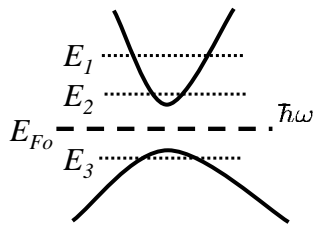
$$n \approx N_c \exp\left(\frac{-(E_c - E_{F_n})}{k_B T}\right)$$

$$p \approx N_v \exp\left(\frac{-(E_{F_v} - E_p)}{k_B T}\right)$$

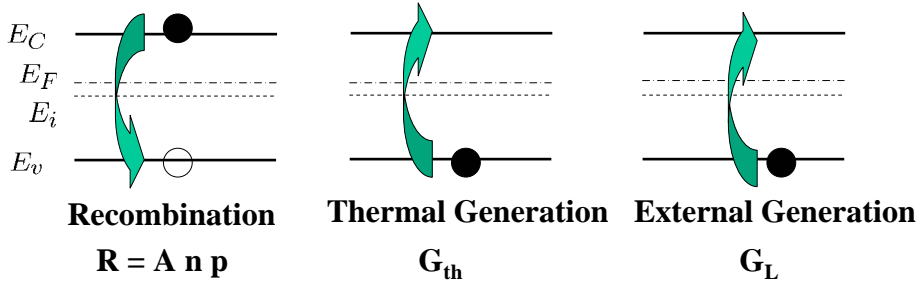
$$np = n_i^2 \exp\left(\frac{-(E_{F_n} - E_{F_p})}{k_B T}\right)$$

Near Equilibrium Electron Distributions

Optical Excitation



Example: Generation and Recombination



Charge conservation: $\frac{d}{dt}(n + p) = 0$

Rate equation: $\frac{d}{dt}n = G_{th} + G_L - R$

In **equilibrium**, every process and its reverse balances, and no drive ($G_L=0$)



$$G_{th} = R_o = A n_o p_o$$

$$G_{th} = A n_o p_o$$

Rate equation becomes: $\frac{d}{dt}n = G_L - A[np - n_o p_o]$

Example

$$\frac{d}{dt}n = G_L - A[np - n_o p_o]$$

Define the excess carriers as n' , then $n = n_o + n'$ and $p = p_o + p'$

$$\frac{d}{dt}n' = G_L - A[n'(n_o + p_o) - n'^2]$$

Consider a special case of low level injection in n-type, that is, $n_o \gg p_o$, and $n' \ll n_o$, then



$$\frac{d}{dt}n' = G_L - \underbrace{A n_o}_{\tau} n'$$

$$n' = n'(0)e^{-t/\tau} + G_L \tau (1 - e^{-t/\tau}) \rightarrow G_L \tau$$

Steady state solution

In steady state $n' = G_L \tau$ so that

$n = n_o + n' \approx n_o$ and $p = p_o + n'$

Recall that in the Boltzmann limit,

$$n = N_c \exp\left(\frac{-(E_c - E_{Fn})}{k_B T}\right) = n_o \exp\left(\frac{-(E_F - E_{Fn})}{k_B T}\right)$$

$$p = N_v \exp\left(\frac{-(E_{Fp} - E_v)}{k_B T}\right) = p_o \exp\left(\frac{-(E_{Fp} - E_F)}{k_B T}\right)$$

Since we know n and p from the rate equations we can find

$$E_{Fn} = E_{Fo} + k_B T \ln(1 + n'/n_o) \approx E_{Fo} + k_B T (n'/n_o) \approx E_{Fo}$$

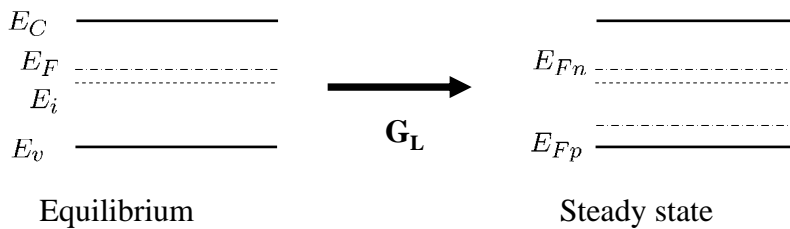
$$E_{Fp} = E_{Fo} - k_B T \ln(1 + n'/p_o) \quad \text{Moves towards the holes}$$

Summary: Steady state solution

In steady state $n' = G_L \tau$

$$E_{Fn} = E_{Fo} + k_B T \ln(1 + n'/n_o) \approx E_{Fo} + k_B T (n'/n_o) \approx E_{Fo}$$

$$E_{Fp} = E_{Fo} - k_B T \ln(1 + n'/p_o) \quad \text{Moves towards the holes}$$



Quasi-equilibrium Transport

Peek into future lectures: Assume that during steady state transport the system can be described by quasi-fermi levels:

$$n(r) \approx N_c \exp\left(\frac{-(E_c(r) - E_{F_c})}{k_B T}\right) \quad \Rightarrow \quad E_{F_c} = E_c(r) + k_B T \ln \frac{n(r)}{N_c}$$

Furthermore assume that the current density given by

$$J_{n_x} \approx \mu_n n \frac{dE_{F_c}}{dx}$$

$$= \mu_n n \frac{dE_c}{dx} + \mu_n n k_B T \frac{N_c}{n} \frac{1}{N_c} \frac{dn}{dx}$$

$$= \mu_n n \frac{dE_c}{dx} + \mu_n k_B T \frac{dn}{dx}$$

$$= \mu_n n q E_x + \mu_n k_B T \frac{dn}{dx}$$

$$E_c(x) = E_{c0} - q\phi(x)$$

$$\frac{dE_c(x)}{dx} = -q \frac{d\phi(x)}{dx} = qE_x$$

Assuming $\frac{\mu}{q} = \frac{D}{k_B T} \quad \Rightarrow$

$$J_{n_x} \equiv q\mu_n n E_x + qD_n \frac{dn}{dx}$$

We still have lots to do before we can prove each major assumption